NSN 5961-01-021-2612

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-021-2612 **Inclosure Material:** Glass and metal **Overall Length:** 0.210 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Current Rating Per Characteristic:** 50.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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